

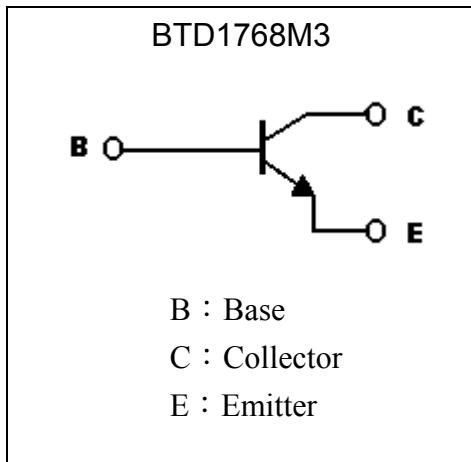
# NPN Epitaxial Planar Transistor

# BTD1768M3

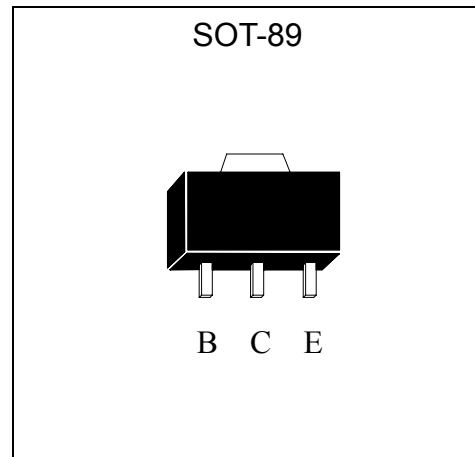
## Features

- High  $V_{CEO}$ ,  $V_{CEO}=80V$
- High  $I_C$ ,  $I_{C(DC)}=1A$
- Low  $V_{CE(sat)}$
- Good current gain linearity
- Complementary to BTB1198M3
- Pb-free lead plating and halogen-free package

## Symbol

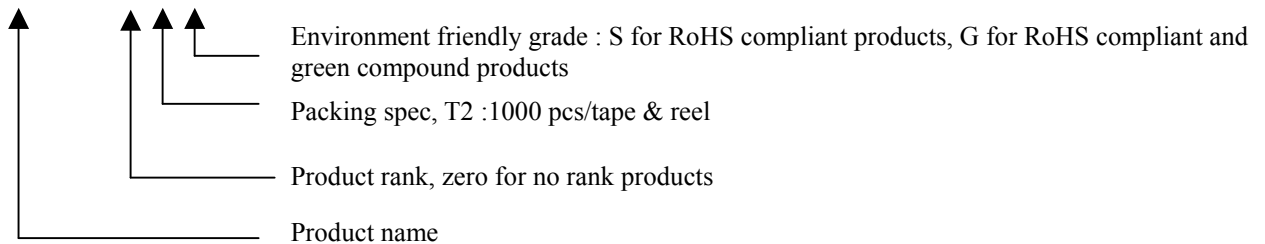


## Outline



## Ordering Information

Device	Package	Shipping
BTD1768M3-X-T2-G	SOT-89 (Pb-free lead plating and halogen-free package)	1000 pcs / Tape & Reel





**Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V <sub>CB0</sub>	100	V
Collector-Emitter Voltage	V <sub>CE0</sub>	80	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current (DC)	I <sub>C</sub>	1	A
Collector Current (Pulse)	I <sub>CP</sub>	2 (Note 1)	A
Power Dissipation	P <sub>d</sub>	0.6	W
		1 (Note 2)	W
		2 (Note 3)	W
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	208	°C/W
		125 (Note 2)	°C/W
		62.5 (Note 3)	°C/W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55~+150	°C

- Note : 1. Single Pulse Pw ≤ 350μs, Duty ≤ 2%.  
 2. When mounted on FR-4 PCB with area measuring 10×10×1 mm  
 3. When mounted on ceramic with area measuring 40×40×1 mm

**Characteristics (Ta=25°C)**

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV <sub>CB0</sub>	100	-	-	V	I <sub>C</sub> =50μA, I <sub>E</sub> =0
BV <sub>CE0</sub>	80	-	-	V	I <sub>C</sub> =1mA, I <sub>B</sub> =0
BV <sub>EBO</sub>	5	-	-	V	I <sub>E</sub> =50μA, I <sub>C</sub> =0
I <sub>CB0</sub>	-	-	1	μA	V <sub>CB</sub> =80V, I <sub>E</sub> =0
I <sub>EBO</sub>	-	-	1	μA	V <sub>EB</sub> =4V, I <sub>C</sub> =0
*V <sub>CE(sat)</sub>	-	-	0.3	V	I <sub>C</sub> =500mA, I <sub>B</sub> =20mA
*h <sub>FE</sub>	120	-	390	-	V <sub>CE</sub> =3V, I <sub>C</sub> =100mA
f <sub>T</sub>	-	100	-	MHz	V <sub>CE</sub> =10V, I <sub>C</sub> =50mA, f=100MHz
C <sub>ob</sub>	-	20	-	pF	V <sub>CB</sub> =10V, f=1MHz

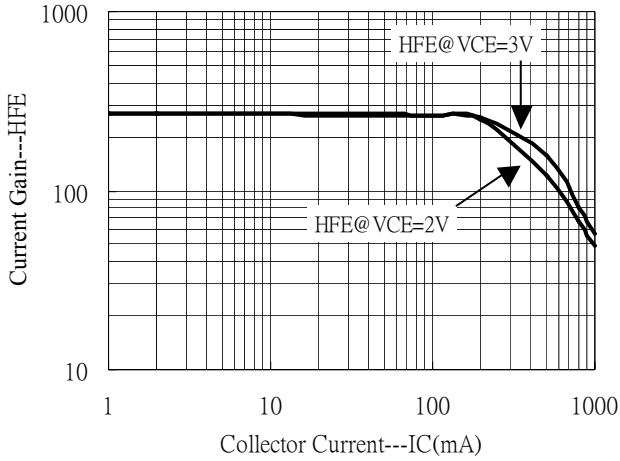
\*Pulse Test : Pulse Width ≤ 380μs, Duty Cycle ≤ 2%

**Classification Of hFE**

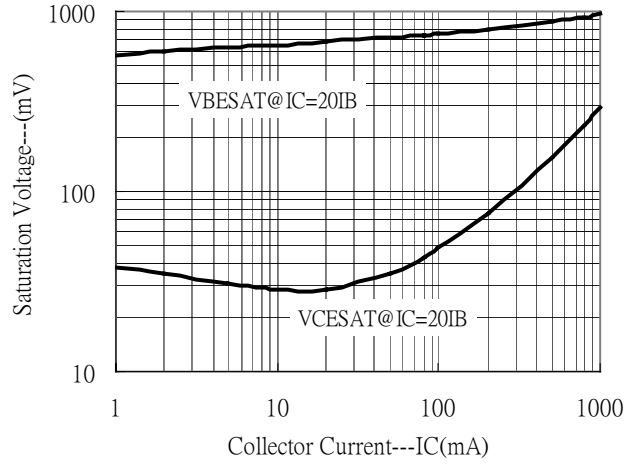
Rank	Q	R
Range	120~270	180~390

**Typical Characteristics**

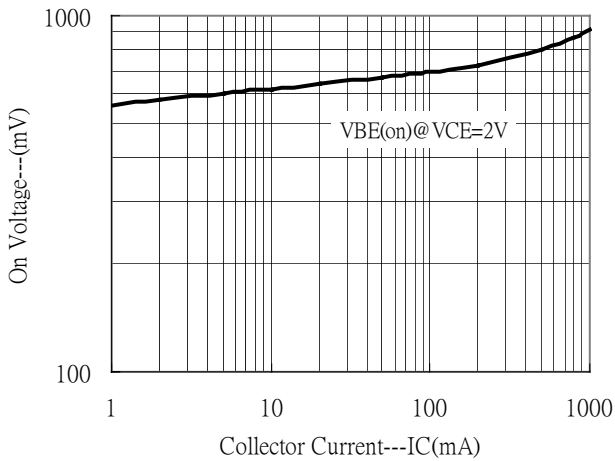
Current Gain vs Collector Current



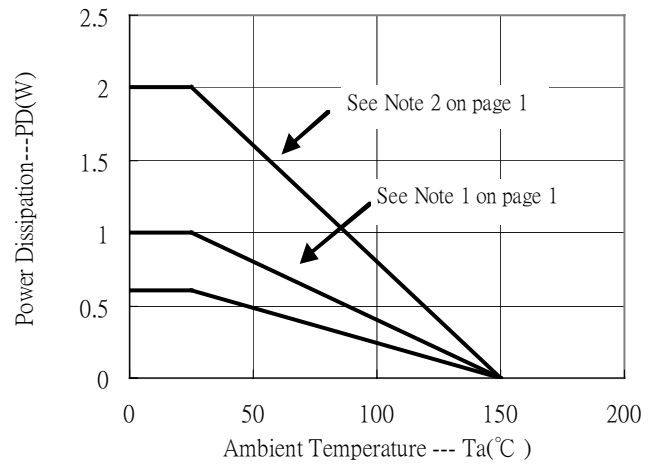
Saturation Voltage vs Collector Current



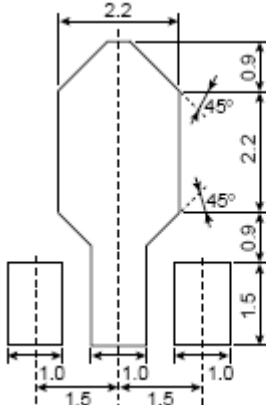
On Voltage vs Collector Current



Power Derating Curves

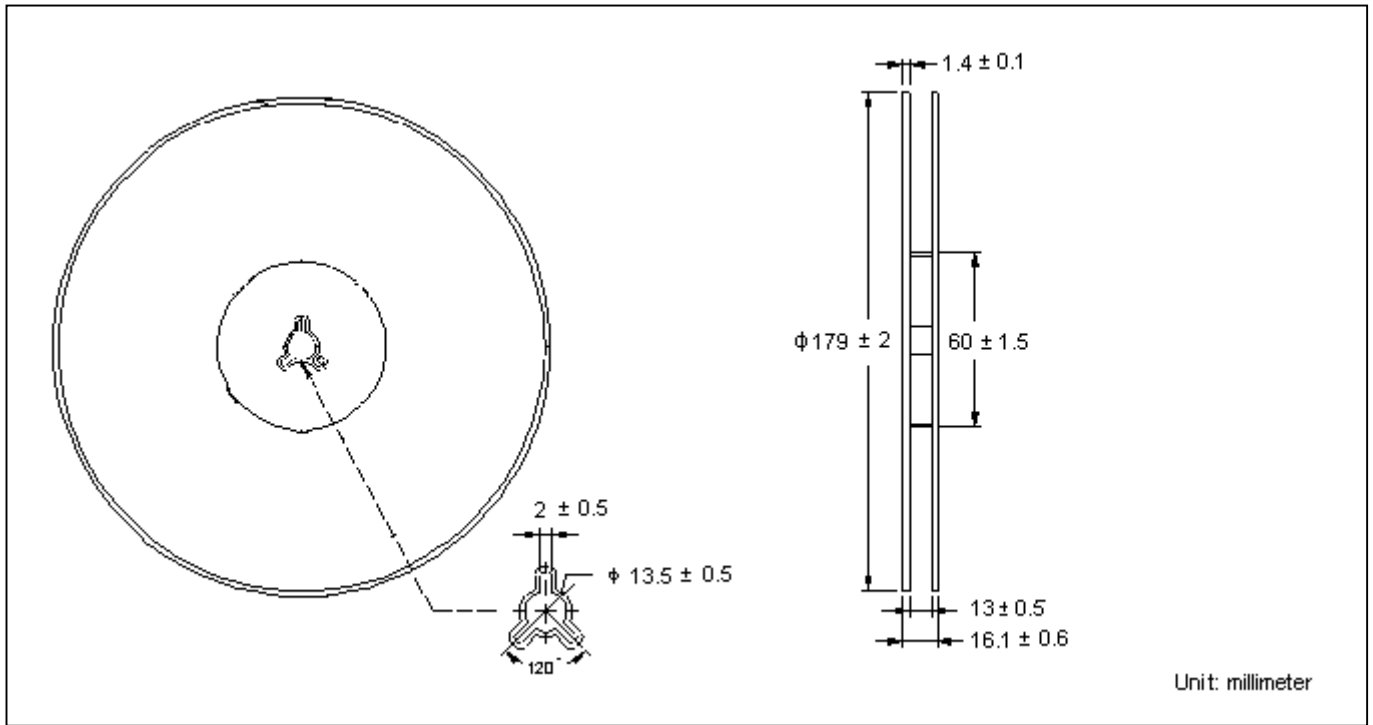


**Recommended soldering footprint**

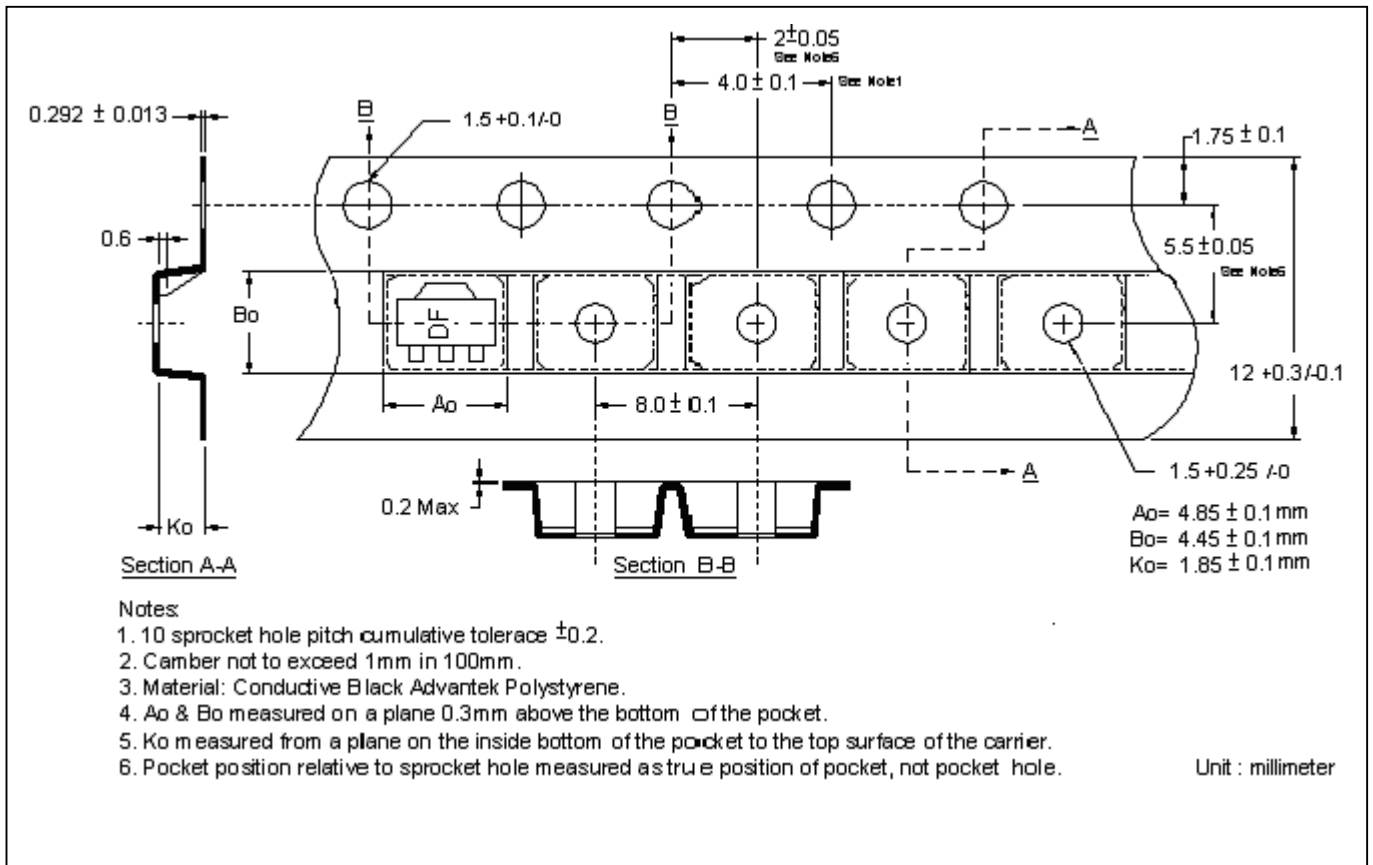


unit : mm

**Reel Dimension**

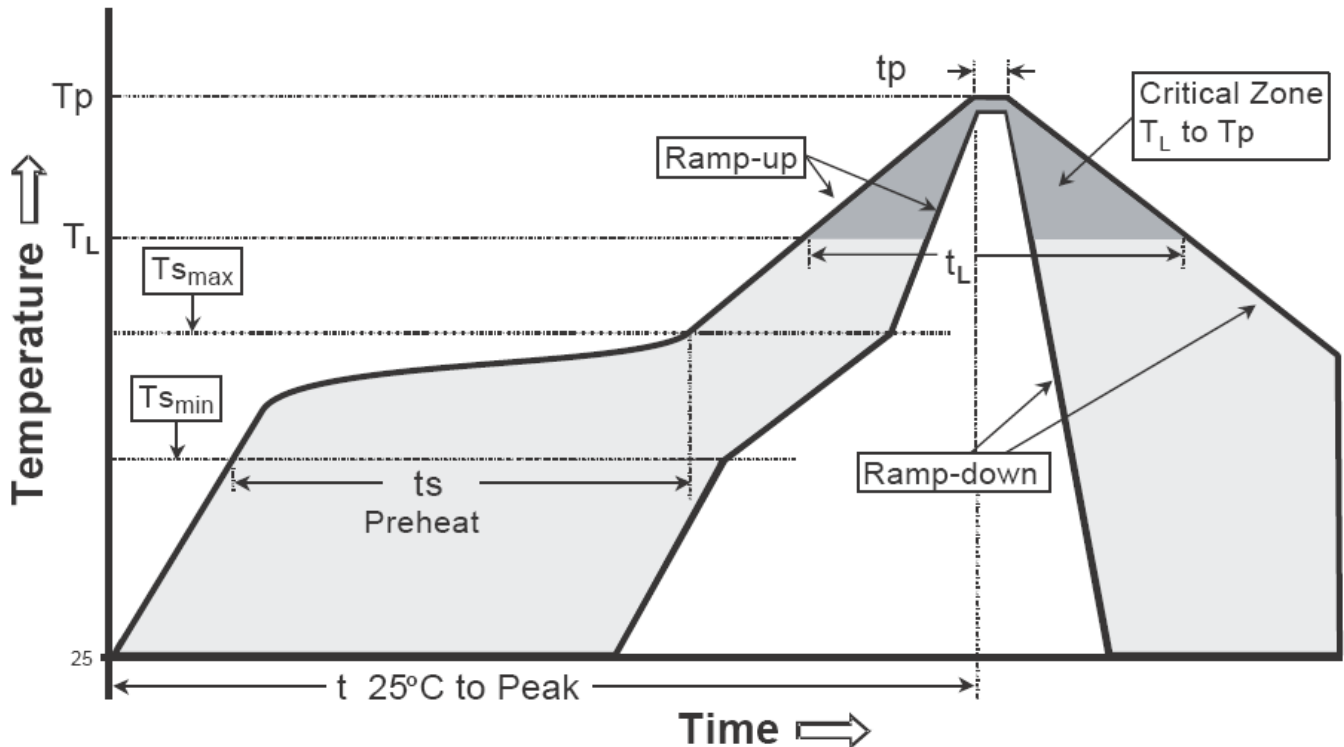


**Carrier Tape Dimension**



**Recommended wave soldering condition**

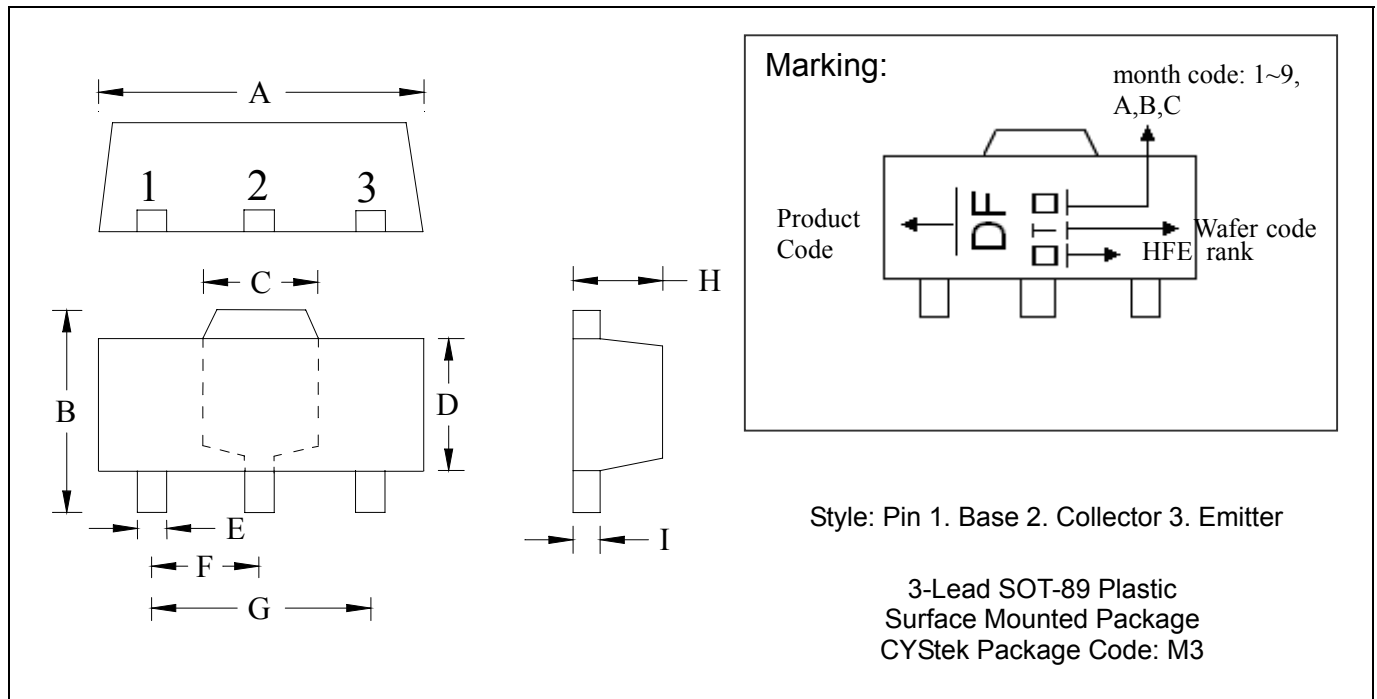
Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

**Recommended temperature profile for IR reflow**


Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T <sub>smax</sub> to T <sub>p</sub> )	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(T <sub>s min</sub> )	100°C	150°C
-Temperature Max(T <sub>s max</sub> )	150°C	200°C
-Time(t <sub>s min</sub> to t <sub>s max</sub> )	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (T <sub>L</sub> )	183°C	217°C
- Time (t <sub>L</sub> )	60-150 seconds	60-150 seconds
Peak Temperature(T <sub>P</sub> )	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

**SOT-89 Dimension**



\*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1732	0.1811	4.40	4.60	F	0.0591	TYP	1.50	TYP
B	0.1551	0.1673	3.94	4.25	G	0.1181	TYP	3.00	TYP
C	0.0610	REF	1.55	REF	H	0.0551	0.0630	1.40	1.60
D	0.0906	0.1024	2.30	2.60	I	0.0138	0.0173	0.35	0.44
E	0.0126	0.0205	0.32	0.52					

Notes: 1.Controlling dimension: millimeters.  
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.  
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

**Material:**

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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